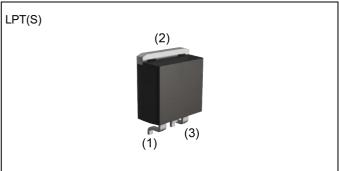
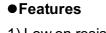


| V <sub>DSS</sub>           | 650V   |
|----------------------------|--------|
| R <sub>DS(on)</sub> (Max.) | 1.050Ω |
| Ι <sub>D</sub>             | ±4.0A  |
| P <sub>D</sub>             | 58W    |

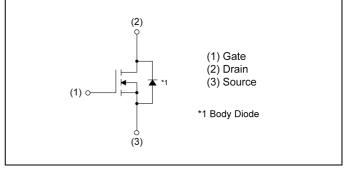
# Outline



## Inner circuit



- 1) Low on-resistance
- 2) Fast switching speed
- 3) Parallel use is easy
- 4) Pb-free plating ; RoHS compliant



# Application

Switching

# Packaging specifications

| Packing                   | Embossed Tape |
|---------------------------|---------------|
| Packing code              | TL            |
| Marking                   | R6504ENJ      |
| Basic ordering unit (pcs) | 1000          |

# • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

| Parameter                               | Symbol           | Value              | Unit |    |
|---|------------------|--------------------|------|----|
| Drain - Source voltage                  |                  | V <sub>DSS</sub>   | 650  | V  |
| Continuous drain current $(T_c = 25)$   | 5°C)             | ۱ <sub>D</sub> *1  | ±4.0 | Α  |
| Pulsed drain current                    |                  | I <sub>DP</sub> *2 | ±12  | Α  |
| Coto Courros voltario                   | Static           | N/                 | ±20  | V  |
| Gate - Source voltage                   | AC(f>1Hz)        | V <sub>GSS</sub>   | ±30  | V  |
| Avalanche current, single pulse         |                  | I <sub>AS</sub>    | 0.8  | А  |
| Avalanche energy, single pulse          |                  | E <sub>AS</sub> *3 | 34.8 | mJ |
| Power dissipation $(T_c = 25^{\circ}C)$ | P <sub>D</sub>   | 58                 | W    |    |
| Junction temperature                    | Τ <sub>j</sub>   | 150                | °C   |    |
| Operating junction and storage te       | T <sub>stg</sub> | -55 to +150        | °C   |    |

## •Thermal resistance

| Deremeter                                    | Cumph of          | Values |      |      | Lincit |
|--|-------------------|--------|------|------|--------|
| Parameter                                    | Symbol            | Min.   | Тур. | Max. | Unit   |
| Thermal resistance, junction - case          | $R_{thJC}^{*4}$   | -      | -    | 2.2  | °C/W   |
| Thermal resistance, junction - ambient       | $R_{thJA}^{*5}$   | -      | -    | 80   | °C/W   |
| Soldering temperature, wavesoldering for 10s | T <sub>sold</sub> | -      | -    | 265  | °C     |

# •Electrical characteristics (T<sub>a</sub> = 25°C)

| Parameter                                      | Sumbol                 | Conditions                                   | Values |       |       | Unit |  |
|--|------------------------|--|--------|-------|-------|------|--|
| Parameter                                      | Symbol                 | Conditions                                   | Min.   | Тур.  | Max.  | Unit |  |
| Drain - Source breakdown<br>voltage            | V <sub>(BR)DSS</sub>   | V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA   | 650    | -     | -     | V    |  |
|  |                        | V <sub>DS</sub> = 650V, V <sub>GS</sub> = 0V |        |       |       |      |  |
| Zero gate voltage<br>drain current             | I <sub>DSS</sub>       | $T_j = 25^{\circ}C$                          | -      | -     | 100   | μA   |  |
|  |                        | T <sub>j</sub> = 125°C                       | -      | -     | 1000  |      |  |
| Gate - Source leakage current                  | I <sub>GSS</sub>       | $V_{GS}$ = ±20V, $V_{DS}$ = 0V               | -      | -     | ±100  | nA   |  |
| Gate threshold voltage                         | $V_{GS(th)}$           | $V_{DS} = V_{GS}, I_D = 130 \mu A$           | 2      | -     | 4     | V    |  |
|  |                        | V <sub>GS</sub> = 10V, I <sub>D</sub> = 1.5A |        |       |       |      |  |
| Static drain - source<br>on - state resistance | R <sub>DS(on)</sub> *6 | $T_j = 25^{\circ}C$                          | -      | 0.955 | 1.050 | Ω    |  |
|  |                        | $T_j = 125^{\circ}C$                         | -      | -     | -     |      |  |
| Gate resistance                                | $R_G$                  | f = 1MHz, open drain                         | -      | 16.7  | -     | Ω    |  |



# •Electrical characteristics (T<sub>a</sub> = 25°C)

| Deremeter                               | Symbol                                     | Conditions                          | Values |      |      | Unit |
|---|--|-------------------------------------|--------|------|------|------|
| Parameter                               | Symbol                                     | Conditions                          | Min.   | Тур. | Max. | Unit |
| Input capacitance                       | C <sub>iss</sub>                           | V <sub>GS</sub> = 0V                | -      | 220  | -    |      |
| Output capacitance                      | C <sub>oss</sub>                           | V <sub>DS</sub> = 25V               | -      | 320  | -    | pF   |
| Reverse transfer capacitance            | erse transfer capacitance C <sub>rss</sub> |                                     | -      | 55   | -    |      |
| Turn - on delay time                    | t <sub>d(on)</sub> *6                      | $V_{DD} \simeq 300 V, V_{GS}$ = 10V | -      | 15   | -    |      |
| Rise time                               | t <sub>r</sub> *6                          | I <sub>D</sub> = 2A                 | -      | 20   | -    | 20   |
| Turn - off delay time $t_{d(off)}^{*6}$ |  | $R_L \simeq 150\Omega$              | -      | 55   | -    | ns   |
| Fall time                               | t <sub>f</sub> *6                          | R <sub>G</sub> = 10Ω                | -      | 45   | -    |      |

# • Gate charge characteristics (T<sub>a</sub> = 25°C)

| Deremeter            | O: make al             | Conditions                        | Values |      |      | Unit |
|----------------------|------------------------|-----------------------------------|--------|------|------|------|
| Parameter            | Symbol Conditions      |                                   | Min.   | Тур. | Max. | Unit |
| Total gate charge    | $Q_g^{*6}$             | $V_{DD} \simeq 300 V$             | -      | 15   | -    |      |
| Gate - Source charge | Q <sub>gs</sub> *6     | I <sub>D</sub> = 4A               | -      | 2.5  | -    | nC   |
| Gate - Drain charge  | Q <sub>gd</sub> *6     | V <sub>GS</sub> = 10V             | -      | 7.5  | -    |      |
| Gate plateau voltage | V <sub>(plateau)</sub> | $V_{DD} \simeq 300V$ , $I_D = 4A$ | -      | 5.6  | -    | V    |

\*1 Limited only by maximum channel temperature allowed.

- \*2 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%
- \*3 L $\doteqdot$ 100mH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , STARTING T<sub>i</sub>=25°C
- \*4 T<sub>C</sub>=25°C
- \*5 Mounted on an epoxy PCB FR4 (25mm x 27mm x 0.8mm)
- \*6 Pulsed



# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

| Parameter                     | Symbol             | Conditions                                | Values |      |      | Unit |  |
|-------------------------------|--------------------|---|--------|------|------|------|--|
| Parameter                     | Symbol             | Conditions                                | Min.   | Тур. | Max. | Unit |  |
| Source current                | ا <sub>S</sub> *1  |   |        | -    | 4.0  | А    |  |
| Pulsed source current         | $I_{SP}^{*2}$      | T <sub>C</sub> = 25°C                     | -      | -    | 12   | А    |  |
| Source-Drain voltage          | $V_{SD}^{*6}$      | V <sub>GS</sub> = 0V, I <sub>S</sub> = 4A | -      | -    | 1.5  | V    |  |
| Reverse recovery time         | t <sub>rr</sub> *6 |   | -      | 270  | -    | ns   |  |
| Reverse recovery charge       | Q <sub>rr</sub> *6 | I <sub>S</sub> = 4A<br>di/dt = 100A/µs    | -      | 1.8  | -    | μC   |  |
| Peak reverse recovery current | ۲ <sub>rr</sub> *6 |   | -      | 13   | -    | А    |  |





150

## • Electrical characteristic curves

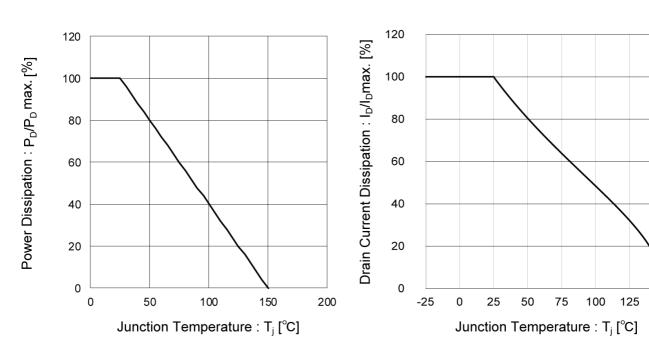


Fig.1 Power Dissipation Derating Curve

Fig.2 Drain Current Derating Curve

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

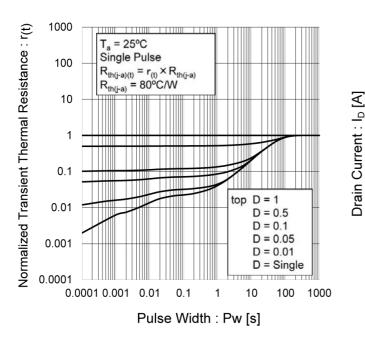
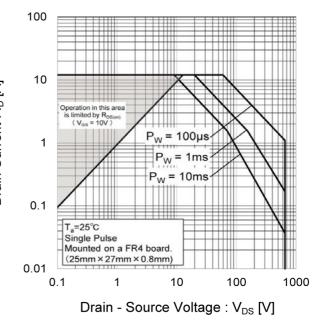


Fig.4 Maximum Safe Operating Area





## • Electrical characteristic curves

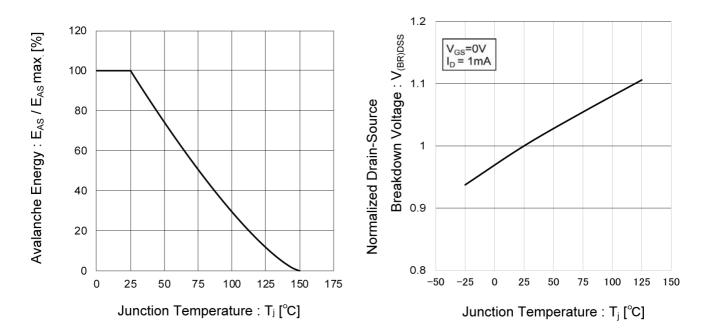
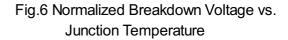


Fig.5 Avalanche Energy Derating Curve



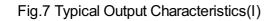
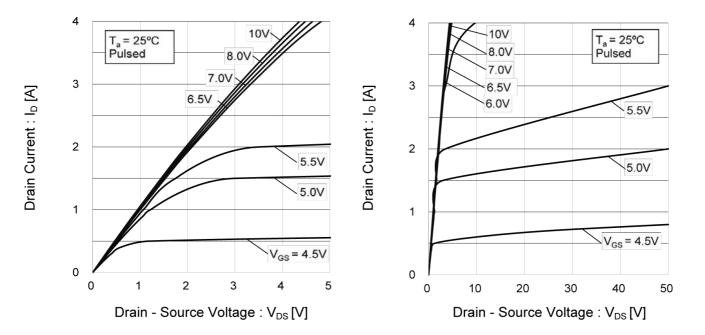
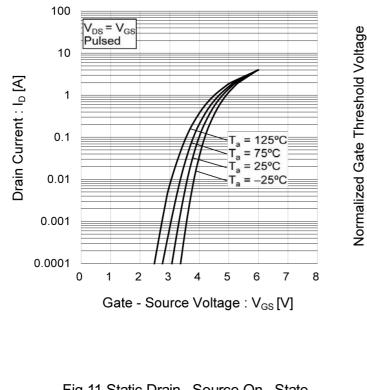


Fig.8 Typical Output Characteristics(II)





## • Electrical characteristic curves



# Fig.9 Typical Transfer Characteristics

Fig.10 Normalized Gate Threshold Voltage vs. Junction Temperature

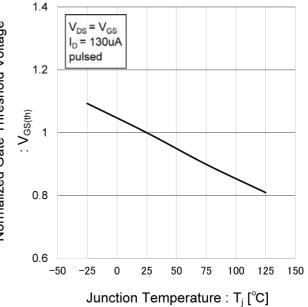
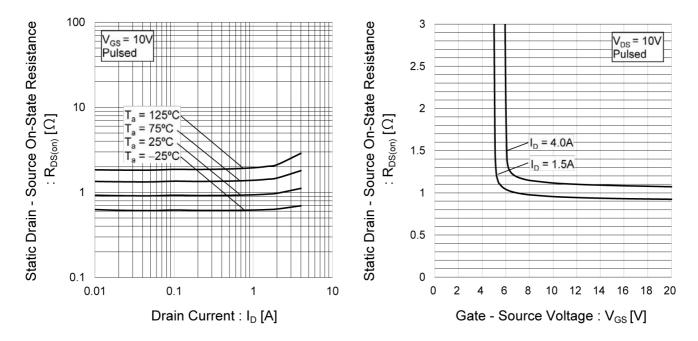


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage





## •Electrical characteristic curves

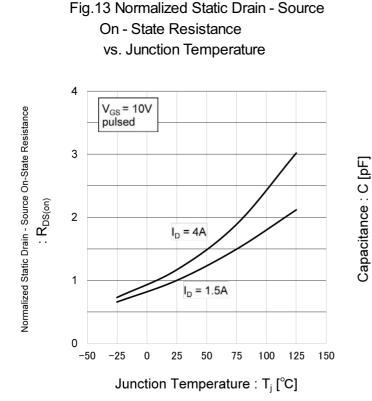


Fig.14 Typical Capacitance vs. Drain - Source Voltage

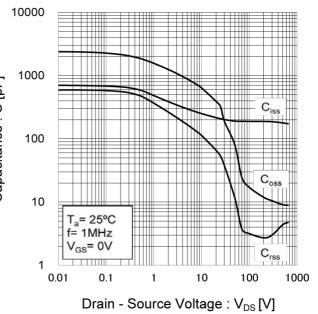


Fig.15 Switching Characteristics

Fig.16 Typical Gate Charge

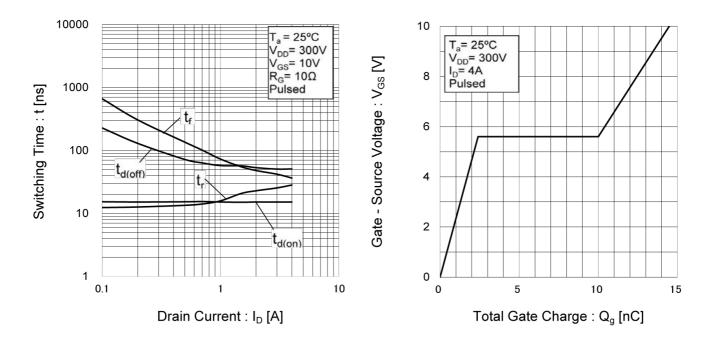




Fig.18 Reverse Recovery Time vs.

Inverse Diode Forward Current

## • Electrical characteristic curves

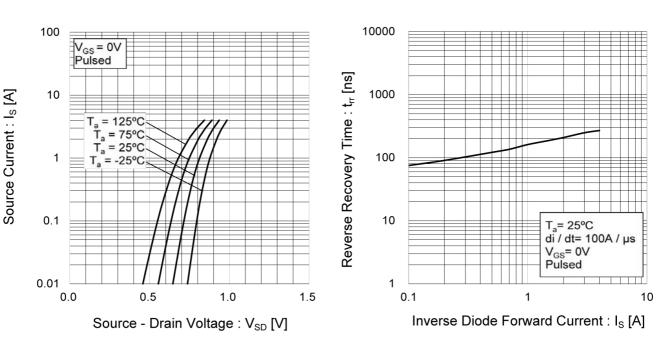


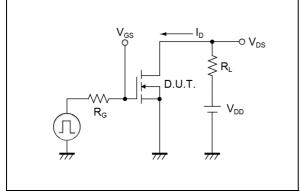
Fig.17 Source Current vs. Source - Drain Voltage



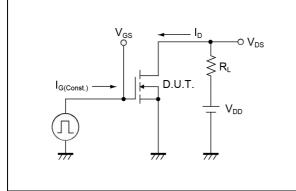


## Measurement circuits

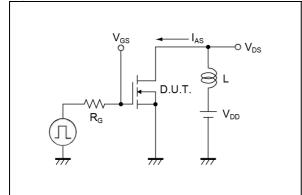
Fig.1-1 Switching Time Measurement Circuit



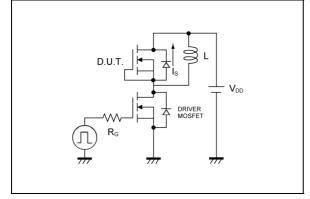
#### Fig.2-1 Gate Charge Measurement Circuit



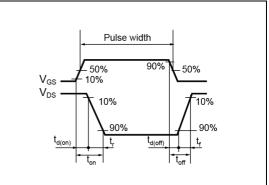
## Fig.3-1 Avalanche Measurement Circuit



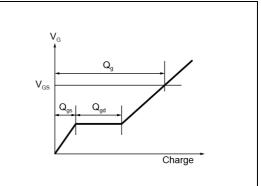
## Fig.4-1 trr Measurement Circuit



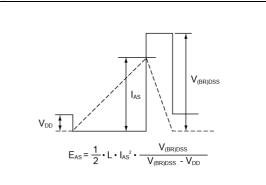
### Fig.1-2 Switching Waveforms



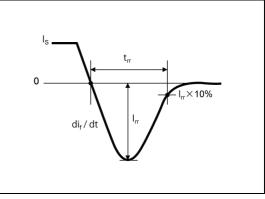
#### Fig.2-2 Gate Charge Waveform



## Fig.3-2 Avalanche Waveform

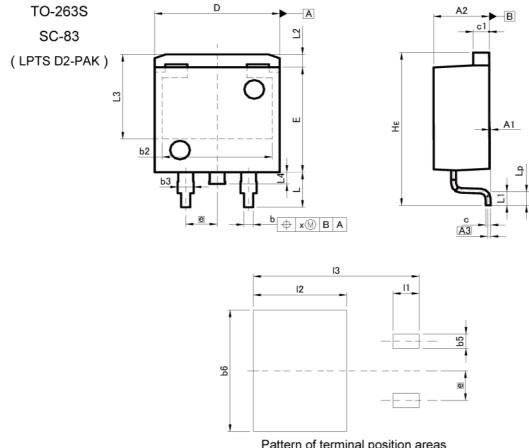


#### Fig.4-2 trr Waveform





## Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

| DIM | MILIM       | ETERS | INC         | HES   |  |
|-----|-------------|-------|-------------|-------|--|
| DIM | MIN         | MAX   | MIN         | MAX   |  |
| A1  | 0.00        | 0.30  | 0.000       | 0.012 |  |
| A2  | 4.30        | 4.70  | 0.169       | 0.185 |  |
| A3  | 0.:         | 25    | 0.0         | 010   |  |
| b   | 0.68        | 0.98  | 0.027       | 0.039 |  |
| b2  | 8.          | 90    | 0.3         | 350   |  |
| b3  | 1.14        | 1.44  | 0.045       | 0.057 |  |
| C   | 0.30        | 0.60  | 0.012       | 0.024 |  |
| c1  | 1.10        | 1.50  | 0.043       | 0.059 |  |
| D   | 9.80        | 10.40 | 0.386       | 0.409 |  |
| E   | 8.80        | 9.20  | 0.346       | 0.362 |  |
| e   | 2.          | 54    | 0.1         | 00    |  |
| HE  | 12.80       | 13.40 | 0.504       | 0.528 |  |
| L   | 2.70        | 3.30  | 0.106       | 0.130 |  |
| L1  | 1.          | 20    | 0.047       |       |  |
| L2  | 1.          | 10    |             | 043   |  |
| L3  | 7.:         | 25    | 0.2         | 285   |  |
| L4  |             | 00    |             | )39   |  |
| Lp  | 0.90        | 1.50  | 0.035       | 0.059 |  |
| x   | <b>A</b>    | 0.25  | -           | 0.010 |  |
|     | MILIM       | ETERS | INC         | HES   |  |
| DIM | MIN         | MAX   | MIN         | MAX   |  |
| b5  | <del></del> | 1.23  | -           | 0.049 |  |
| b6  | <del></del> | 10.40 | · · · · · · | 0.409 |  |
| 11  | <u> </u>    | 2.10  | <u>, 12</u> | 0.083 |  |
| 12  |             | 7.55  | 1.<br>1.    | 0.297 |  |
| 13  | -           | 13.40 | -           | 0.528 |  |

Dimension in mm/inches





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|---|--------|---------|------------|---------|
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|   | CLASSⅣ | CLASSII | CLASSII    | CLASSI  |

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  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
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- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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